

# **ISC Silicon NPN Power Transistor**

### **DESCRIPTION**

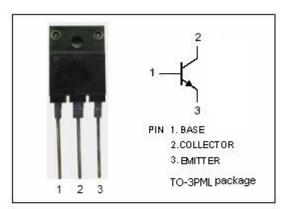
- · High Collector-Emitter Breakdown Voltage-
  - : V<sub>(BR)CEO</sub>= 400V(Min)
- · High Switching Speed
- High Reliability
- · Minimum Lot-to-Lot variations for robust device performance and reliable operation

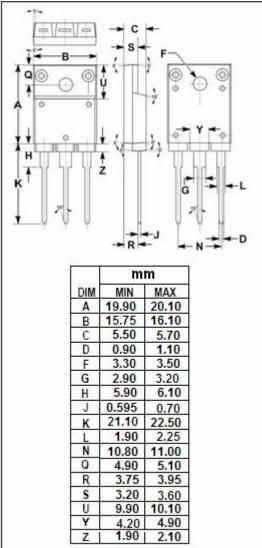
### **APPLICATIONS**

• Designed for switching regulator and general purpose applications.

## ABSOLUTE MAXIMUM RATINGS(Ta=25℃)

SYMBOL	PARAMETER	VALUE	UNIT
Vсво	Collector-Base Voltage	500	V
V <sub>CEO</sub>	Collector-Emitter Voltage	400	V
V <sub>EBO</sub>	Emitter-Base voltage	7	V
Ic	Collector Current-Continuous	12	А
Ісм	Collector Current-Peak	25	Α
l <sub>Β</sub>	Base Current-Continuous	4	Α
Pc	Collector Power Dissipation @ Tc=25℃	55	W
TJ	Junction Temperature	150	$^{\circ}$
T <sub>stg</sub>	Storage Temperature Range	-55~150	°C







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2SC4423

### **ELECTRICAL CHARACTERISTICS**

Tc=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT
V <sub>(BR)CEO</sub>	Collector-Emitter Breakdown Voltage	I <sub>C</sub> = 25mA ; I <sub>B</sub> = 0	400			V
V <sub>CE(sat)</sub>	Collector-Emitter Saturation Voltage	I <sub>C</sub> = 8A; I <sub>B</sub> =1.6A			0.8	V
V <sub>BE(sat)</sub>	Base-Emitter Saturation Voltage	Ic= 8A; I <sub>B</sub> = 1.6A			1.5	V
I <sub>CBO</sub>	Collector Cutoff Current	V <sub>CB</sub> = 400V ; I <sub>E</sub> = 0			10	uA
I <sub>EBO</sub>	Emitter Cutoff Current	V <sub>EB</sub> = 5V; I <sub>C</sub> = 0			10	uA
h <sub>FE-1</sub>	DC Current Gain	I <sub>C</sub> =1.6A; V <sub>CE</sub> = 5V	15		50	
h <sub>FE-2</sub>	DC Current Gain	I <sub>C</sub> =8A; V <sub>CE</sub> = 5V	10			
h <sub>FE-3</sub>	DC Current Gain	I <sub>C</sub> =10mA ; V <sub>CE</sub> = 5V	10			
Сов	Output Capacitance	I <sub>E</sub> = 0 ; V <sub>CB</sub> = 10V; f <sub>test</sub> =1.0MHz		85		pF
f⊤	Current-Gain—Bandwidth Product	I <sub>E</sub> = -1.5A ; V <sub>CE</sub> = 12V		10		MHz

### ♦ h<sub>FE-1</sub> Classifications

L	М	N
15-30	20-40	30-50

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